

## Features

- 80Watts peak pulse power ( $T_p = 8/20\mu s$ )
- DFN1006-2 package
- Bidirectional configurations
- Low clamping voltage
- Low leakage current
- Solid-state silicon-avalanche technology
- Protection one data/power line to:  
IEC 61000-4-2  $\pm 30\text{kV}$  contact  $\pm 30\text{kV}$  air  
IEC 61000-4-4 (EFT) 40A (5/50ns)  
IEC 61000-4-5 (Lightning) 10A (8/20 $\mu s$ )



## Mechanical Data

- **Case:** DFN1006-2 (plastic package).  
Lead free; RoHS compliant; Halogen free
- **Molding Compound Flammability Rating:**  
UL 94 V-0
- **Terminals:** High temperature soldering guaranteed:  
260 °C/10 sec. at terminals

## Applications

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

## Absolute Maximum Ratings

Ratings at 25 °C, ambient temperature unless otherwise specified

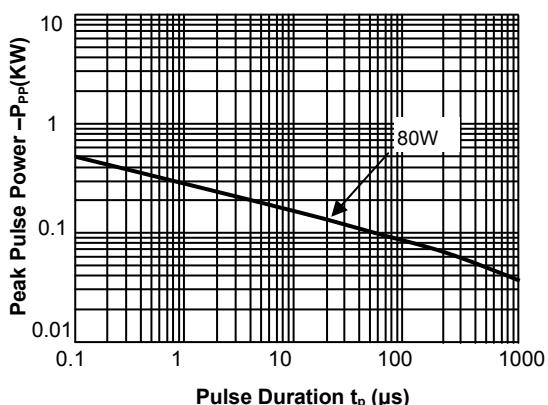
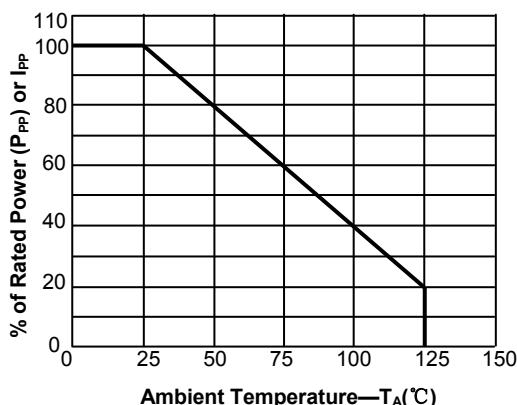
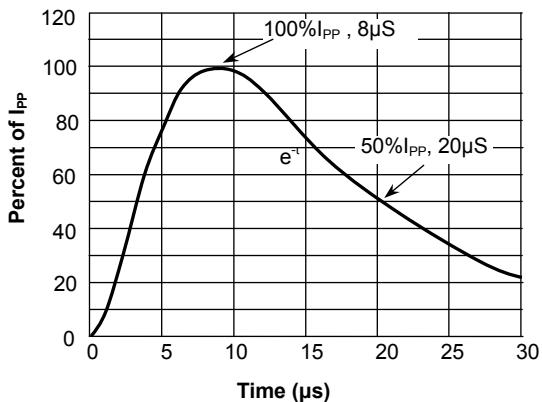
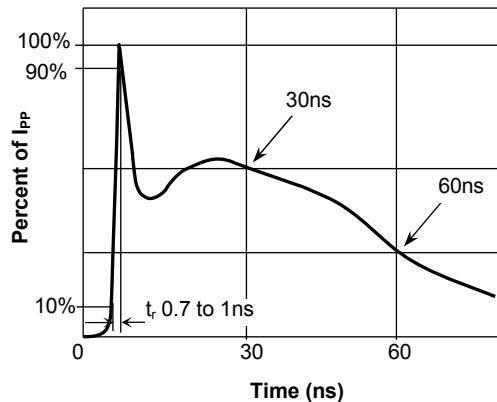
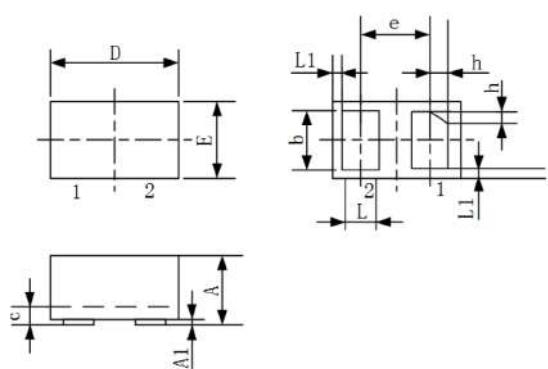
Parameter	Symbol	Value	Unit
Peak Pulse Power ( $T_p=8/20\mu s$ )	$P_{PP}$	80	W
ESD contact/air discharge (IEC-61000-4-2)	$V_{ESD}$	30/30	kV
Peak Pulse Current ( $t_p = 8/20\mu s$ )	$I_{PP}$	10	A
Junction Temperature	$T_J$	-55 to +125	°C
Storage temperature	$T_{STG}$	-55 to +125	°C

## Electrical Characteristics

( $T_A = 25$  °C unless otherwise specified)

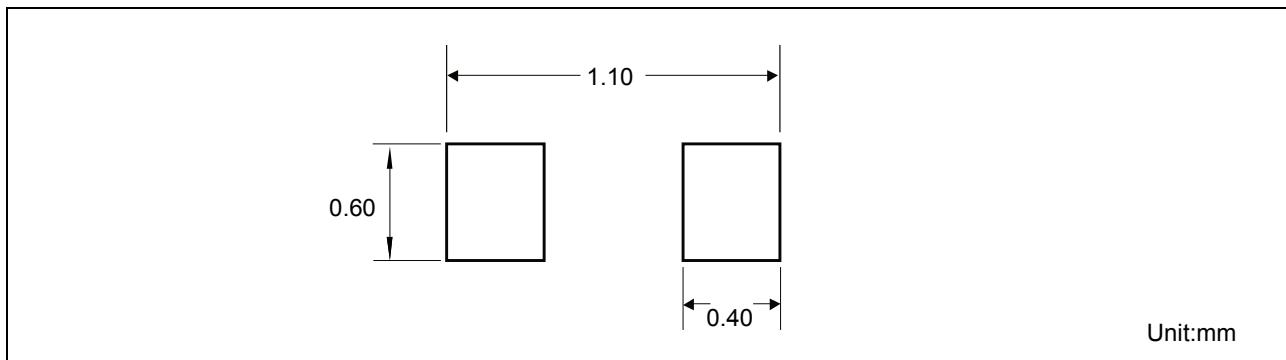
Parameter	Symbol	Conditions	Min	Typical	Max	Unit
Reverse Stand-Off Voltage	$V_{RWM}$				3.3	V
Reverse Breakdown Voltage	$V_{BR}$	$I_T=1\text{mA}$	4.1			V
Reverse Leakage Current	$I_R$	$V_{RWM}=3.3\text{V}, T=25^\circ\text{C}$		0.1	0.2	µA
Clamping Voltage	$V_{CL}$	$I_{PP}=16\text{A}, t_p=100\text{ns}$		8		V
Clamping Voltage	$V_C$	$I_{PP}=5\text{A}, t_p=8/20\mu s$			6	V
Clamping Voltage		$I_{PP}=10\text{A}, t_p=8/20\mu s$		8		V
Dynamic resistance	$R_{DYN}$			0.2		Ω
Junction Capacitance	$C_j$	$V_R = 0\text{V}, f = 1\text{MHz}$		15		pF

**Typical Characteristics** ( $T_{amb} = 25^{\circ}\text{C}$  unless otherwise specified)

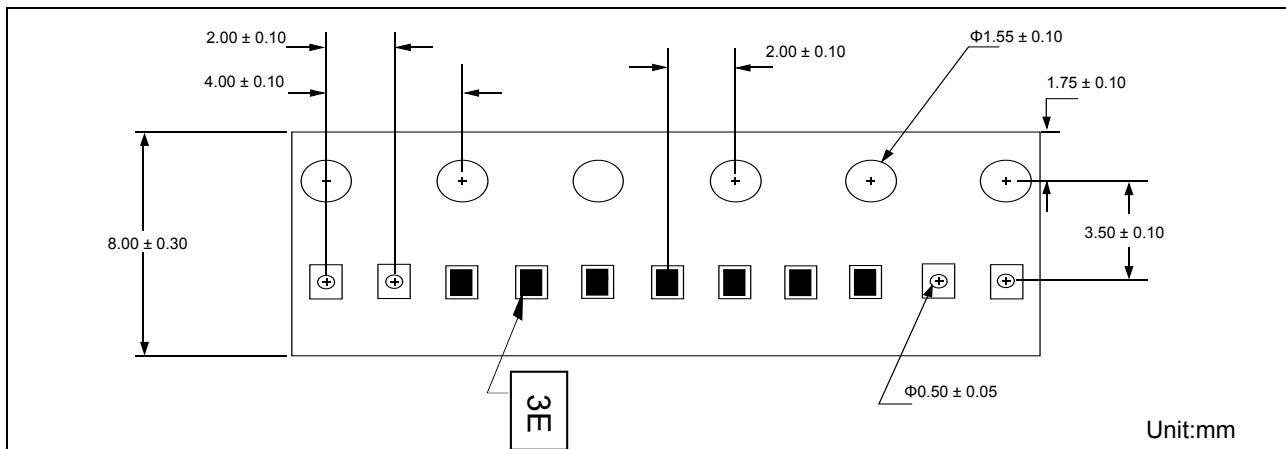
**Fig.1 Peak Pulse Power Rating Curve**

**Fig.2 Pulse Derating Curve**

**Fig.3 Pulse Waveform-8/20μs**

**Fig.4 Pulse Waveform-ESD(IEC61000-4-2)**

**Package Dimensions**


Symbol	Dimensions in millimeters		
	Min	Nom	Max
D	0.95	1.00	1.05
E	0.55	0.60	0.65
b	0.45	0.50	0.55
L	0.20	0.25	0.30
e	0.65 BSC		
A	0.45	0.50	0.55
A1	0	0.02	0.05
c	0.12	0.15	0.18
h	0.07	0.12	0.17
L1	0.05 REF		

### Pad Dimensions



### Tape and Reel Specification



### Marking



### Ordering information

Order code	Package	Packaging option	Base quantity	Packaging specification
YEDD1023R10AG	DFN1006-2	Tape and reel	10000pcs / reel	EIA STD RS-481